

MJD148

NPN Silicon Power Transistor

DPAK for Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- High Gain
- Low Saturation Voltage
- High Current Gain – Bandwidth Product
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	45	Vdc
Collector-Base Voltage	V_{CB}	45	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous	I_C	4.0	Adc
Collector Current – Peak	I_{CM}	7.0	Adc
Base Current	I_B	50	mAdc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	20 0.16	W W/ $^\circ\text{C}$
Total Power Dissipation (Note 1) @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.75 0.014	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	C	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

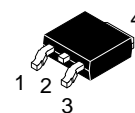
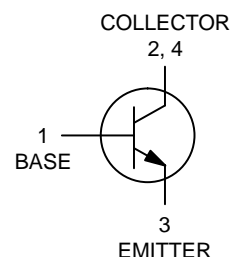
1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.



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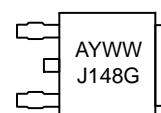
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POWER TRANSISTOR 4.0 AMPERES 45 VOLTS, 20 WATTS



DPAK
CASE 369C
STYLE 1

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
J148 = Device Code
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping†
MJD148T4G	DPAK (Pb-Free)	2,500/Tape & Reel
NJVMJD148T4G	DPAK (Pb-Free)	2,500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	$^{\circ}\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	71.4	$^{\circ}\text{C}/\text{W}$

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}\text{C}$, unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage (Note 3) ($I_C = 100 \text{ mAdc}$, $I_B = 0$)	$V_{CEO(sus)}$	45	-	Vdc
Collector Cutoff Current ($V_{CB} = 45 \text{ Vdc}$, $I_E = 0$)	I_{CBO}	-	20	μAdc
Emitter Cutoff Current ($V_{BE} = 5 \text{ Vdc}$, $I_C = 0$)	I_{EBO}	-	1	mAdc

ON CHARACTERISTICS (Note 3)

DC Current Gain ($I_C = 10 \text{ mAdc}$, $V_{CE} = 5 \text{ Vdc}$) ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 1 \text{ Vdc}$) ($I_C = 2 \text{ Adc}$, $V_{CE} = 1 \text{ Vdc}$) ($I_C = 3 \text{ Adc}$, $V_{CE} = 1 \text{ Vdc}$)	h_{FE}	40 85 50 30	- 375 - -	-
Collector-Emitter Saturation Voltage ($I_C = 2 \text{ Adc}$, $I_B = 0.2 \text{ Adc}$)	$V_{CE(sat)}$	-	0.5	Vdc
Base-Emitter On Voltage ($I_C = 2 \text{ Adc}$, $V_{CE} = 1 \text{ Vdc}$)	$V_{BE(on)}$	-	1.1	Vdc

DYNAMIC CHARACTERISTICS

Current-Gain-Bandwidth Product ($I_C = 250 \text{ mAdc}$, $V_{CE} = 1 \text{ Vdc}$, $f = 1 \text{ MHz}$)	f_T	3	-	MHz
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2\%$.

TYPICAL CHARACTERISTICS

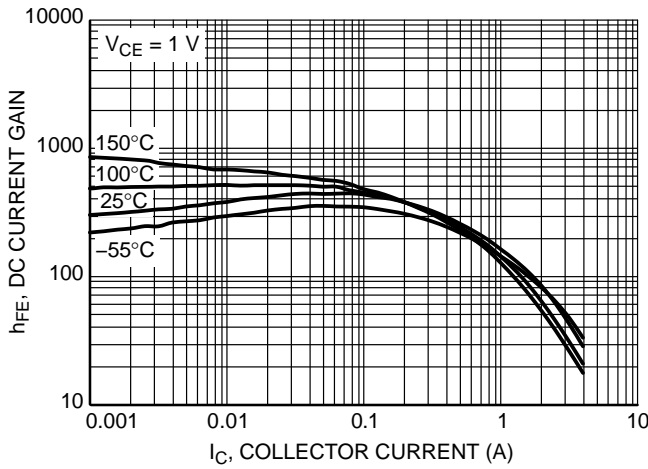


Figure 1. DC Current Gain

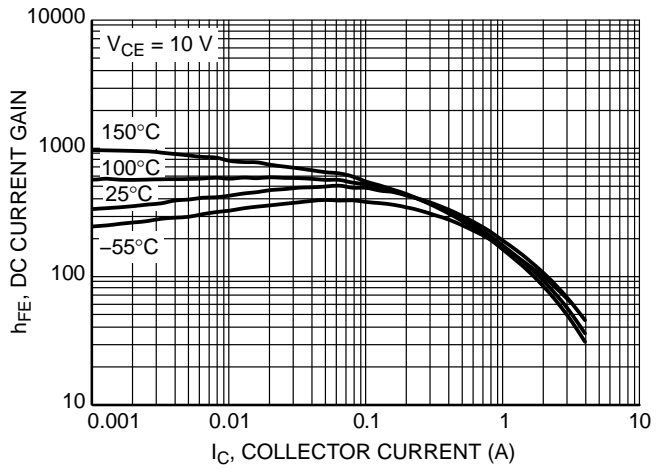


Figure 2. DC Current Gain

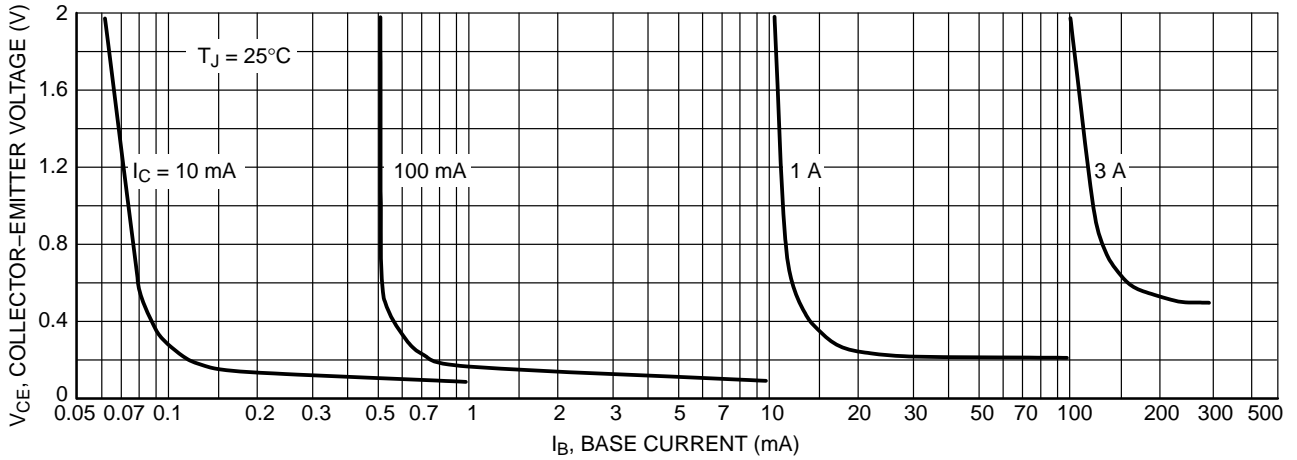


Figure 3. Collector Saturation Region

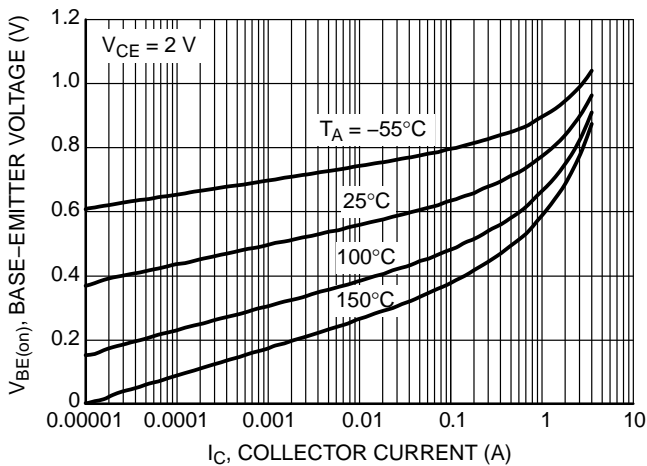


Figure 4. Base Emitter Voltage vs. Collector Current

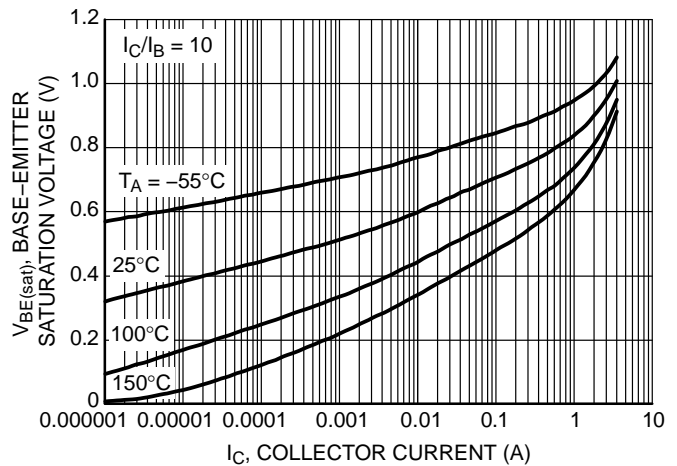


Figure 5. Base Emitter Saturation Voltage vs. Collector Current

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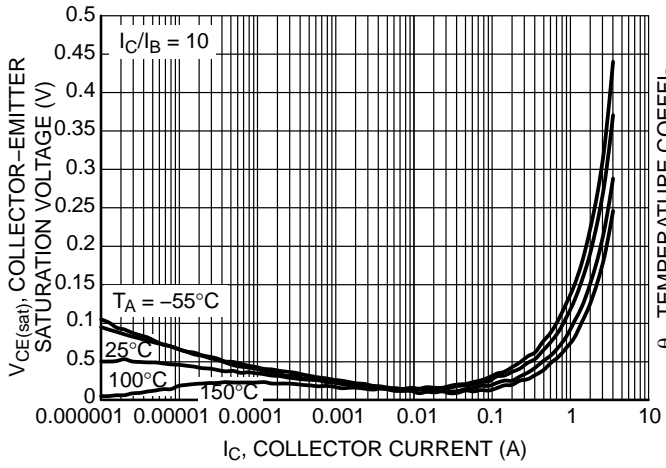


Figure 6. Collector Emitter Saturation Voltage vs. Collector Current

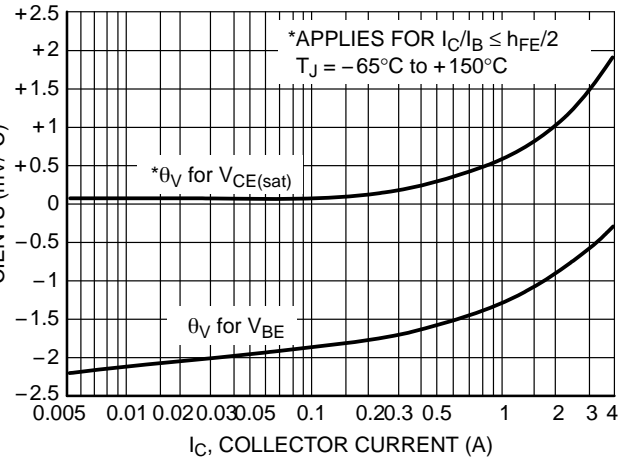


Figure 7. Temperature Coefficients

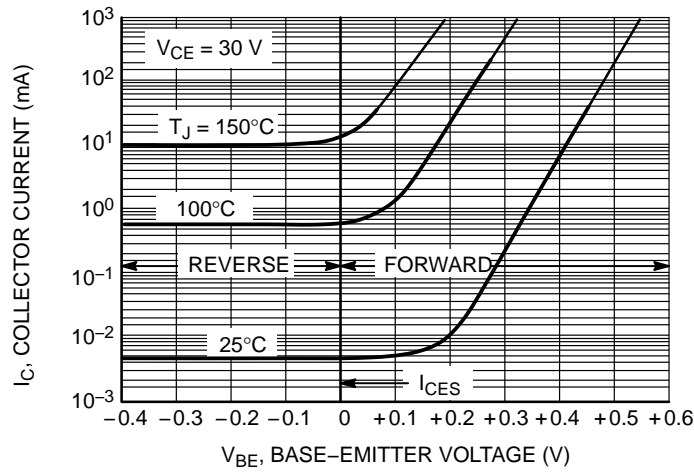


Figure 8. Collector Cut-Off Region

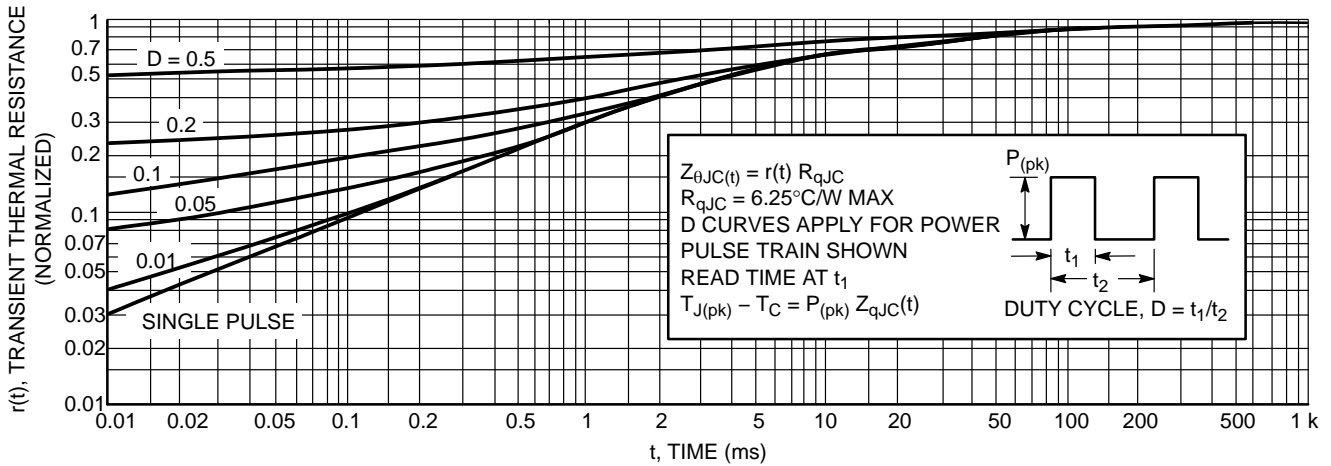


Figure 9. Thermal Response

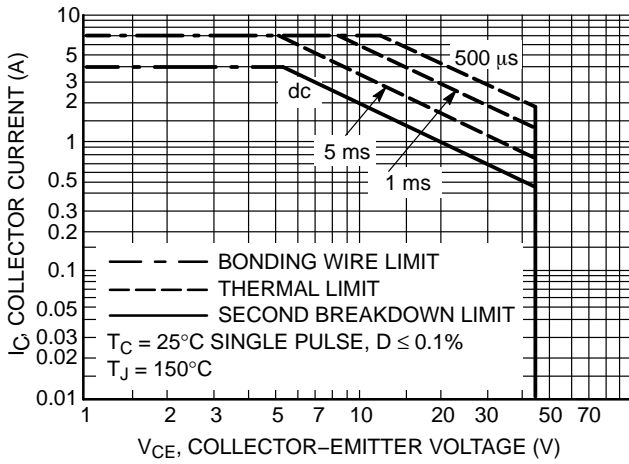


Figure 10. Maximum Rated Forward Bias

Forward Bias Safe Operating Area Information

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 10 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 9. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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